Unit: mm

TOSHIBA Transistor Silicon PNP · NPN Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

# **RN4911FF**

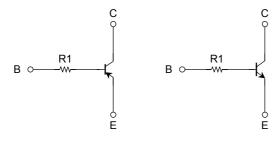
Switching, Inverter Circuit, Interface Circuit and **Driver Circuit Applications.** 

- Two devices are incorporated into an Extreme-Super-Mini (6 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count. Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.

#### **Equivalent Circuit and Bias Resistor Values**

Q1

Q2



R1:  $10 \text{ k}\Omega$ 

(Q1, Q2 common)

6 1.0±0.05 0.2±0.05 1.6±0.05 5

1.6±0.05 1.2±0.05

(E1) 0.12±0.05 1. EMITTER1 2. BASE1 3. COLLECTOR2 (C2) 4. EMITTER2 (E2)

(B2)

5. BASE2 6. COLLECTOR1 (C1) ES6

**JEDEC** JEITA

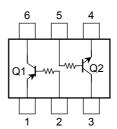
Weight: g (typ.)

TOSHIBA

#### Marking

# VM

## **Equivalent Circuit (top view)**



### Maximum Ratings (Ta = 25°C) (Q1)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	Ic	-100	mA

### Maximum Ratings (Ta = 25°C) (Q2)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	I <sub>C</sub>	100	mA

### Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Collector power dissipation	P <sub>C</sub> (Note)	100	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

Note: Total rating

2

### Electrical Characteristics (Ta = 25°C) (Q1)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-100	nA
DC current gain	h <sub>FE</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ mA}$	120	_	400	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = -5 \text{ mA}, I_B = -0.25 \text{ mA}$	_	-0.1	-0.3	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	_	200	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	3	6	pF

#### Electrical Characteristics (Ta = 25°C) (Q2)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_{E} = 0$	_	_	100	nA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 5 \text{ V}, I_{C} = 0$	_	_	100	nA
DC current gain	h <sub>FE</sub>	$V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ mA}$	120	_	700	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = 5 \text{ mA}, I_B = 0.25 \text{ mA}$	_	0.1	0.3	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA	_	250	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	3	6	pF

# Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input resistor	R1		7	10	13	kΩ

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